

# (19) United States

## (12) Patent Application Publication (10) Pub. No.: US 2021/0033970 A1 Hatakeyama et al.

Feb. 4, 2021 (43) **Pub. Date:** 

### (54) RESIST COMPOSITION AND PATTERNING **PROCESS**

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Appl. No.: 16/919,574

(22)Filed: Jul. 2, 2020

(30)Foreign Application Priority Data

Aug. 2, 2019 (JP) ...... 2019-142948

### **Publication Classification**

(51) Int. Cl. G03F 7/004 (2006.01)G03F 7/039 (2006.01) G03F 7/038 (2006.01)C08F 220/18 (2006.01)C08F 212/14 (2006.01)

U.S. Cl.

CPC ......... G03F 7/0045 (2013.01); G03F 7/0392 (2013.01); G03F 7/0382 (2013.01); G03F 7/162 (2013.01); **C08F 220/1802** (2020.02); C08F 212/24 (2020.02); C08F 220/1806 (2020.02)

#### (57)**ABSTRACT**

A resist composition comprising a base polymer and a quencher in the form of an ammonium salt consisting of an ammonium cation having an iodized aromatic ring bonded to the nitrogen atom via a  $C_1$ - $C_{20}$  hydrocarbylene group which may contain an ester bond or ether bond and a carboxylate anion having an iodized or brominated hydrocarbyl group offers a high sensitivity and minimal LWR or improved CDU, independent of whether it is of positive or negative tone.